## NSN 5961-01-121-9504



Transistor - Page 1 of 2 View Online at https://aerobasegroup.com/nsn/5961-01-121-9504 **Inclosure Material:** Metal **Overall Length:** 1.462 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-63 **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Overall Width Across Flats:** 0.865 inches **Thread Size:** 0.312 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 450.0 breakdown voltage, collector-to-base, emitter open and 10.0 emitter to base voltage, static, collector open and 400.0 breakdown voltage, collector-to-emitter, base open **Current Rating Per Characteristic:** 70.00 amperes source cutoff current and 15.00 amperes source cutoff current **Power Rating Per Characteristic:** 350.0 watts small-signal input power, common-collector **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius ambient air **Special Features:** Junction pattern arrangement: npn **Thread Series Designator:** Unf **Terminal Type And Quantity:** 3 tab, solder lug Shelf Life:

Demilitarization:

**Unit Of Measure:** 

No

N/a

## **NSN 5961-01-121-9504** Transistor - Page 2 of 2



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